This product complies with the RoHS Directive (EU 2002/95/EC).

PNZ102F (PN102F)

Silicon planar type

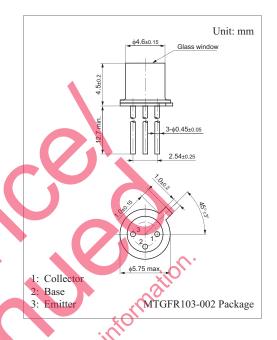
For optical control systems

■ Features

- Low dark current: $I_{CEO} = 5 \text{ nA (typ.)}$
- Fast response: t_n , $t_r = 3 \mu s$ (typ.)
- Wide directivity characteristics

■ Absolute Maximum Ratings $T_a = 25$ °C

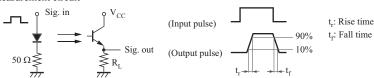
Parameter	Symbol	Rating	Unit	
Collector-emitter voltage (Base open)	V _{CEO}	30	V	
Collector-base voltage (Emitter open)	V_{CBO}	40	V	
Emitter-collector voltage (Base open)	V _{ECO}	5	V	
Emitter-base voltage (Collector open)	V_{EBO}	5	V	
Collector current	I_{C}	50	mA	
Collector power dissipation	P _C	150	mW	
Operating ambient temperature	T _{opr}	-25 to +85	°C .	
Storage temperature	T _{stg}	-30 to +100	°C	



■ Electrical Characteristics $T_a = 25$ °C±3°C

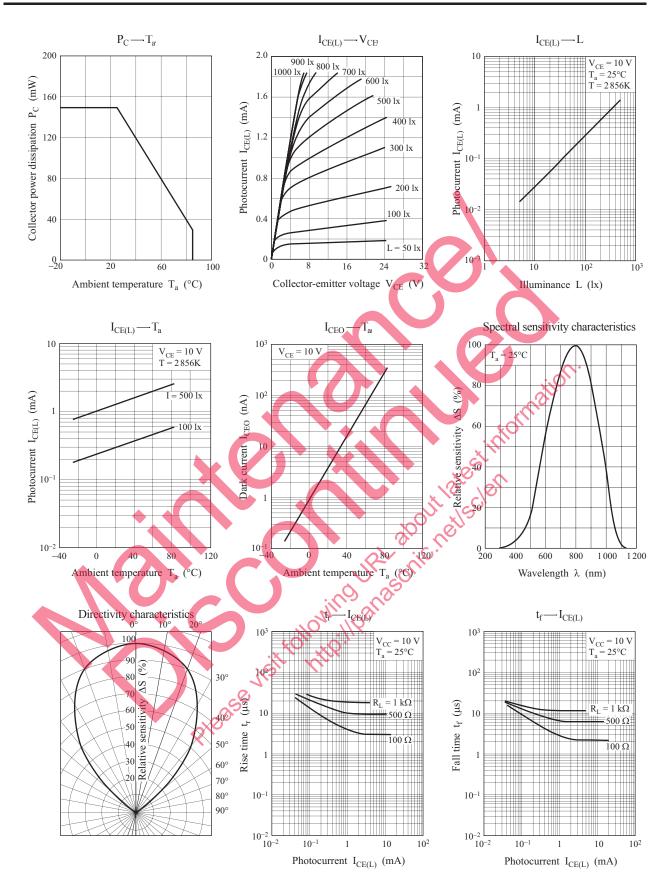
Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Photocurrent *i	I _{CE(L)}	$V_{CH} = 10 \text{ V}, L = 100 \text{ lx}$	0.1	0.3		mA
Dark current	I _{CEO}	$V_{\rm CE} = 10 \rm V$		5	300	nA
Peak sensitivity wavelength	$\lambda_{ m P}$	$V_{CE} = 100$		800		nm
Half-power angle	θ	The angle from which photocurrent becomes 50%		40		0
Rise time *2	t _r	V = 10 V I = 5 m A D = 100 O		3		μs
Fall time *2	45	$V_{CCI} = 10 \text{ V}, I_{CE(L)} = 5 \text{ mA}, R_{LI} = 100 \Omega$		3		μs
Collector-emitter saturation voltage *1	CE(sat)	$I_{CE(L)} = 0.1 \text{ mA}, L = 500 \text{ lx}$		0.2	0.4	V

- Note) 1. Measuring methods are based on JAPANESE INDUSTRIAL STANDARD JIS C 7030 measuring methods for transistors.
 - 2. The rate of electric power reduction is 2.0 mW/°C above $T_a = 25$ °C.
 - 3. Spectral sensitivity characteristics: Sensitivity for wave length over 400 nm maximum sensitivity ratio is 100%.
 - 4. This device is designed by disregarding radiation.
 - 5 *1: Source: Tungsten (color temperature 2 856 K)
 - *2: Switching time measurement circuit



Note) The part number in the parenthesis shows conventional part number.

PNZ102F Panasonic



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